

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

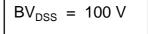
ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, uniotificated use, even if such claim any manner.

Advanced Power MOSFET

IRFP150A

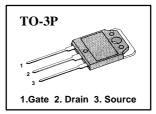
FEATURES

- Avalanche Rugged Technology
- Rugged Gate Oxide Technology
- Lower Input Capacitance
- Improved Gate Charge
- Extended Safe Operating Area
- 175°C Operating Temperature
- Lower Leakage Current : 10 µA (Max.) @ V_{DS} = 100V
- Lower $R_{DS(ON)}$: 0.032 Ω (Typ.)



 $R_{DS(on)} = 0.04 \ \Omega$

 $I_D = 43 A$



Absolute Maximum Ratings

Symbol	Characteristic	Value	Units		
V _{DSS}	Drain-to-Source Voltage		100	V	
	Continuous Drain Current (T _c =25°C)		43	4	
۱ _D	Continuous Drain Current (T _c =100 °C)	30.4	A		
I _{DM}	Drain Current-Pulsed	1	170	А	
V _{GS}	Gate-to-Source Voltage		± 20	V	
E _{AS}	Single Pulsed Avalanche Energy	2	740	mJ	
I _{AR}	Avalanche Current	1	43	А	
E _{AR}	Repetitive Avalanche Energy	Ð	19.3	mJ	
dv/dt	Peak Diode Recovery dv/dt	3	6.5	V/ns	
P	Total Power Dissipation (T _c =25° _C)		193	W	
P _D	Linear Derating Factor		1.28	W/°C	
	Operating Junction and				
T_J , T_STG	Storage Temperature Range		- 55 to +175		
- T	Maximum Lead Temp. for Soldering		200	°C	
TL	Purposes, 1/8" from case for 5-seconds		300		

Thermal Resistance

Symbol	Characteristic	Тур.	Max.	Units
R _{θJC}	Junction-to-Case		0.78	
R _{θCS}	Case-to-Sink	0.24		°C/W
R _{θJA}	Junction-to-Ambient		40	



SEMICONDUCTOR™ ©1999 Fairchild Semiconductor Corporation

IRFP150A

N-CHANNEL POWER MOSFET

Symbol	Characteristic	Min.	Тур.	Max.	Units	Test Condition
BV _{DSS}	Drain-Source Breakdown Voltage	100			V	V _{GS} =0V,I _D =250
$\Delta BV/\Delta T_J$	Breakdown Voltage Temp. Coeff.		0.11		V/°C	I _D =250μA See Fig 7
V _{GS(th)}	Gate Threshold Voltage	2.0		4.0	V	V _{DS} =5V,I _D =250μA
I _{GSS}	Gate-Source Leakage, Forward			100	nA	V _{GS} =20V
GSS	Gate-Source Leakage, Reverse			-100		V _{GS} =-20V
	Droin to Source Laskage Current			10		V _{DS} =100V
I _{DSS}	Drain-to-Source Leakage Current			100	μA	V _{DS} =80V,T _C =150°C
R _{DS(on)}	Static Drain-Source On-State Resistance			0.04	Ω	V _{GS} =10V,I _D =21.5A ④
9 _{fs}	Forward Transconductance		28.34		Ω	V _{DS} =40V,I _D =21.5A ④
C _{iss}	Input Capacitance		1750	2270		
C _{oss}	Output Capacitance		420	485	pF	$V_{GS}=0V, V_{DS}=25V, f=1MHz$
C _{rss}	Reverse Transfer Capacitance		185	215		See Fig 5
t _{d(on)}	Turn-On Delay Time		17	50		V _{DD} =50V,I _D =40A,
t _r	Rise Time		20	50	20	$R_{G} = 6.2\Omega$
t _{d(off)}	Turn-Off Delay Time		80	160	ns	See Fig 13 46
t _f	Fall Time		45	100		
Q _g	Total Gate Charge		75	97		V _{DS} =80V,V _{GS} =10V,
Q _{gs}	Gate-Source Charge		13.2		nC	I _D =40A
Q_{gd}	Gate-Drain("Miller") Charge		34.8			See Fig 6 & Fig 12 46

Electrical Characteristics (T_C=25 $^{\circ}$ C unless otherwise specified)

Source-Drain Diode Ratings and Characteristics

Symbol	Characteristic	Min.	Тур.	Max.	Units	Test Condition
ا _s	Continuous Source Current			43	^	Integral reverse pn-diode
I _{SM}	Pulsed-Source Current ()			170	А	in the MOSFET
V _{SD}	Diode Forward Voltage			1.6	V	T _J =25°C,I _S =43A,V _{GS} =0V
t _{rr}	Reverse Recovery Time		135		ns	T _J =25°C,I _F =40A
Q _{rr}	Reverse Recovery Charge		0.65		μC	di _F /dt=100A/µs ④

Notes;

- O Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- 2 L=0.6mH, I_{AS}=43A, V_{DD}=25V, R_G=27 Ω , Starting T_J=25°C

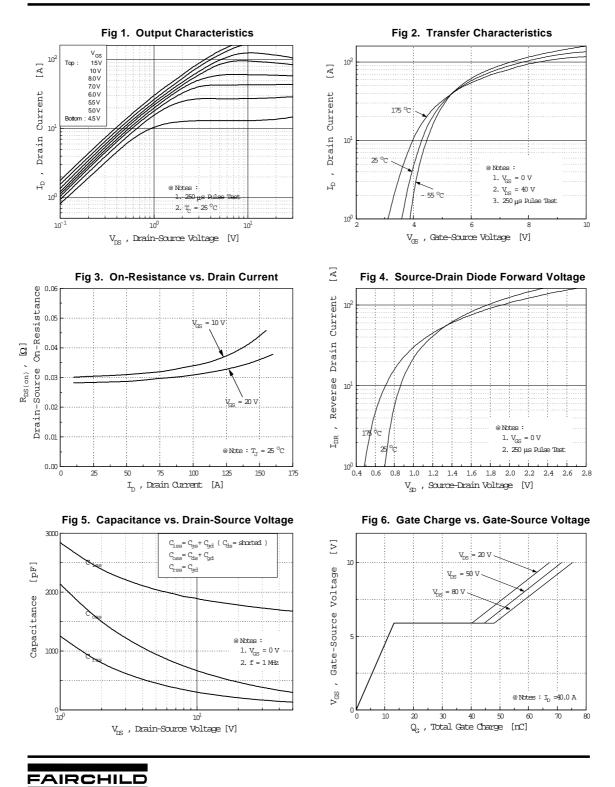
- 5 Essentially Independent of Operating Temperature

FAIRCHILD

SEMICONDUCTOR

N-CHANNEL POWER MOSFET

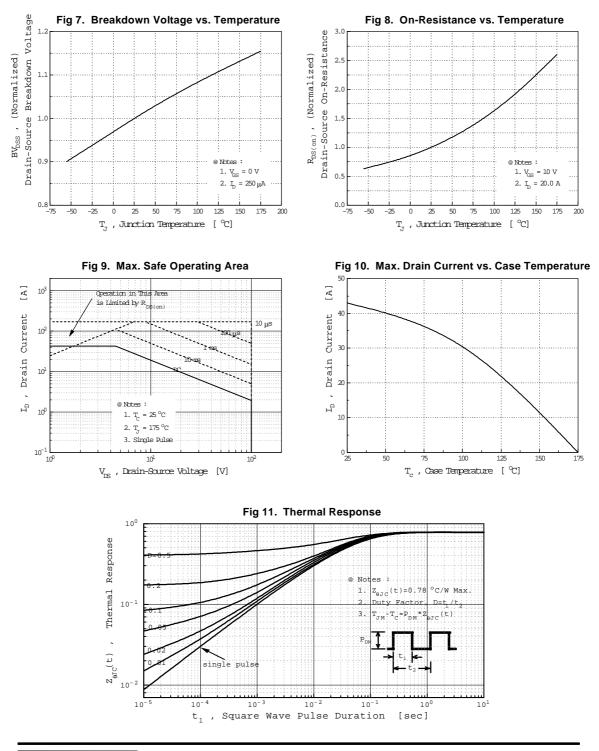
IRFP150A



SEMICONDUCTOR

IRFP150A

N-CHANNEL POWER MOSFET



FAIRCHILD SEMICONDUCTOR

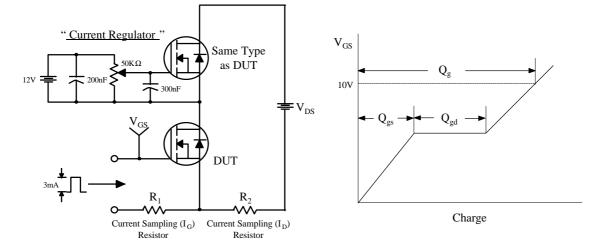
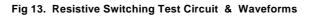


Fig 12. Gate Charge Test Circuit & Waveform



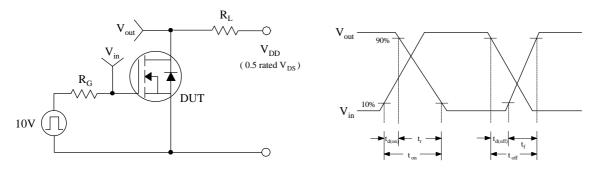
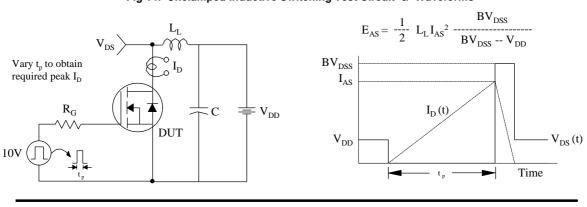


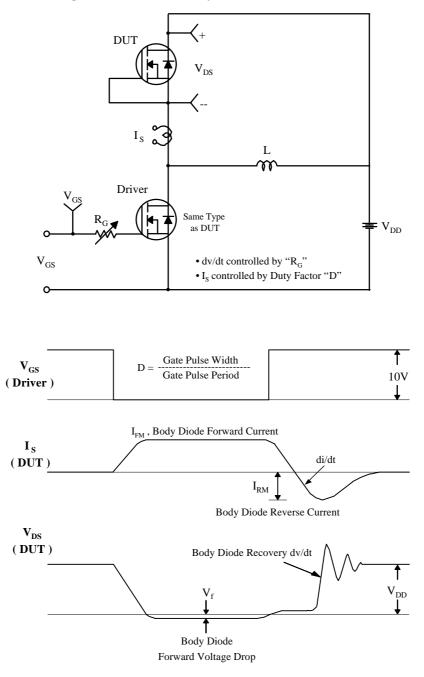
Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

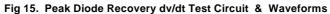




N-CHANNEL

POWER MOSFET







SEMICONDUCTOR

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACExTM CoolFETTM CROSSVOLTTM E²CMOSTM FACTTM FACT Quiet SeriesTM FAST[®] FAST[®] FASTrTM GTOTM HiSeCTM ISOPLANAR[™] MICROWIRE[™] POP[™] PowerTrench[™] QS[™] Quiet Series[™] SuperSOT[™]-3 SuperSOT[™]-6 SuperSOT[™]-8 TinyLogic[™] UHC[™] VCX[™]

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user. 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC